Preliminary

TOSHIBA Photocoupler GaAs IRED&Photo-triac

TLP260J

Triac Drive
Programmable Controllers
AC-Output Module
Solid State Relay

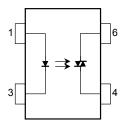
The TOSHIBA TLP260J is a photocoupler housed in a mini-flat package and consists of a phototriac which is optically coupled to a gallium arsenide infrared-emitting diode.

This type of photocoupler is suitable for use in hybrid ICs as it is thinner and smaller than a 6-pin DIP photocoupler.

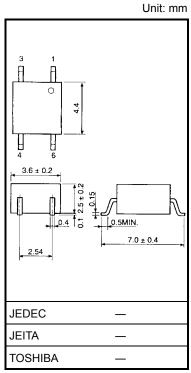
TLP260J: 4-pin mini-flat package (MFSOP6)

- Peak OFF-state voltage: 600 V (min)
- Trigger LED current: 10 mA (max)
- ON-state current: 70 mA (max)
- Isolation voltage: 3000 Vrms (min)

Pin Configuration (top view)



- 1: ANODE
- 3: CATHODE
- 4: TERMINAL1
- 6: TERMINAL2



Weight: 0.09 g

Maximum Ratings (Ta = 25°C)

Characteristics			Symbol	Rating	Unit	
	Forward current		I _F	50	mA	
	Forward current derating (Ta ≥ 5	ΔI _F /°C	-0.7	mA/°C		
LED	Peak forward current (100 μs pu	I _{FP}	1	Α		
	Reverse voltage	V _R	5	V		
	Junction temperature	Tj	125	°C		
	OFF-state output terminal voltage	V_{DRM}	600	V		
	ON-state RMS current	Ta = 25°C	I= (D.40)	70	mA	
		Ta = 70°C	I _T (RMS)	40	IIIA	
ctor	ON-state current derating (Ta ≥	∆I _T /°C	-0.67	mA/°C		
Detector	Peak ON-state current (100 μs pulse, 120 pps)	I _{TP}	2	А		
	Peak nonrepetitive surge current (P _W = 10 ms, DC = 10%)		I _{TSM}	1.2	А	
	Junction temperature		Tj	100	°C	
Storag	Storage temperature range			-55~125	°C	
Opera	Operating temperature range			-40~100	°C	
Lead s	Lead soldering temperature (10 s)			260	°C	
Isolation voltage (AC, 1 min, RH ≤ 60%) (Note1)			BVS	3000	Vrms	

Note 1: Pins 1 and 3 shorted together, and pins 4 and 6 shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	V _{AC}	_	_	240	V _{ac}
Forward current	I _F	15	20	25	mA
Peak ON-state current	I _{TP}	_	_	1	Α
Operating temperature	T _{opr}	-25	_	85	°C

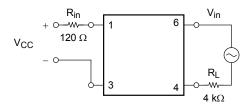
Individual Electrical Characteristics (Ta = 25°C)

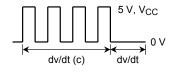
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
LED	Forward voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
	Reverse current	I _R	V _R = 5 V	_	_	10	μА
	Capacitance	C _T	V = 0, f = 1 MHz	_	30	_	pF
Detector	Peak OFF-state current	I _{DRM}	V _{DRM} = 600 V	_	10	1000	nA
	Peak ON-state voltage	V _{TM}	$I_{TM} = 70 \text{ mA}$	_	1.7	2.8	V
	Holding current	lΗ	_	_	1.0	_	mA
	Critical rate of rise of OFF-state voltage	dv/dt	V _{in} = 240 V, Ta = 85°C (Note2)	_	500		V/μs
	Critical rate of rise of commutating voltage	dv/dt (c)	$V_{in} = 60 \text{ Vrms}, I_T = 15 \text{ mA} \text{ (Note2)}$	_	0.2		V/μs

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I _{FT}	$V_T = 6 V$	_	_	10	mA
Capacitance input to output	Cs	V _S = 0, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500 V, RH ≤ 60%	5 × 10 ¹⁰	10 ¹⁴	_	Ω
	BVS	AC, 1 min.	3000	_	_	Vrms
Isolation voltage		AC, 1 s, in oil	_	5000	_	
		DC, 1 min., in oil	_	5000	_	Vdc
Turn-on time	t _{ON}	$V_D = 6 \rightarrow 4 \text{ V}, R_L = 100 \Omega,$ $I_F = \text{Rated } I_{FT} \times 1.5$	_	30	100	μS

Note 2: dv/dt test circuit





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